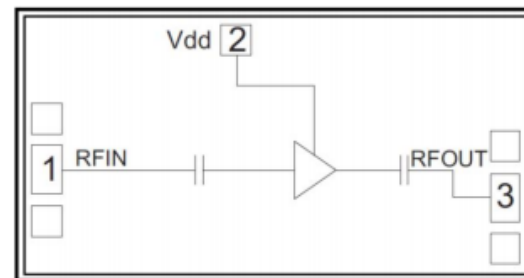


**Features**

- Single Biasing Voltage(Self Biased)
- Frequency: 18-26GHz
- Small Signal Gain: 24.5dB
- Noise Figure: 1.5dB typ.
- P1dB: 13.5dBm
- Psat: 14.5dBm
- Power supply: +5V/50mA
- Input/Output: 50Ω
- Die Size: 1.96 x 0.9 x 0.09 mm

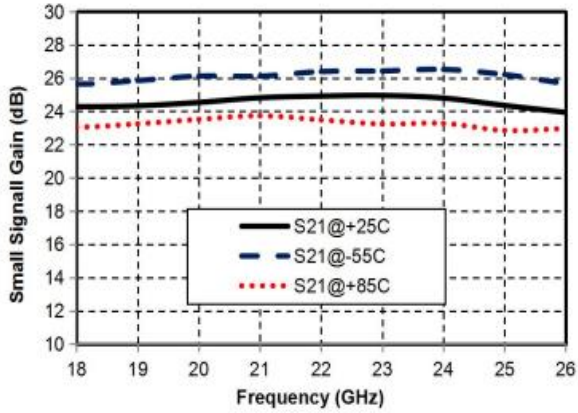
**Typical Applications**

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

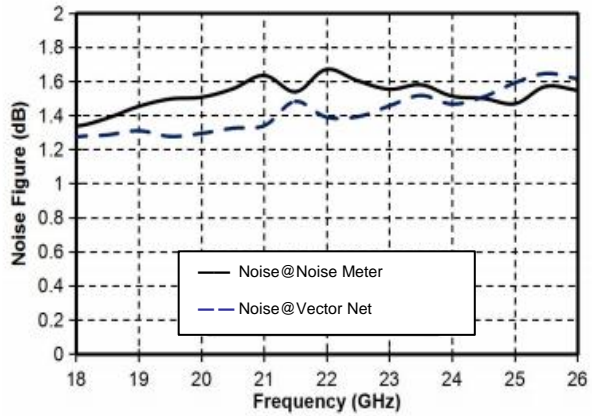
**Functional Block Diagram**

**Electrical Specifications**
**TA = +25°C, Vd = +5V**

Parameters	Min.	Typ.	Max.	Units
<b>Frequency</b>	<b>18-26</b>			<b>GHz</b>
<b>Small Signal Gain</b>	-	<b>24.5</b>	-	<b>dB</b>
<b>Gain Flatness</b>		<b>±0.5</b>		<b>dB</b>
<b>Noise Figure</b>	-	<b>1.5</b>	-	<b>dB</b>
<b>Output 1dB Compression (P1dB)</b>	-	<b>13.5</b>	-	<b>dBm</b>
<b>Psat</b>	-	<b>14.5</b>	-	<b>dBm</b>
<b>Input Return Loss</b>	-	<b>12</b>	-	<b>dB</b>
<b>Output Return Loss</b>	-	<b>15</b>	-	<b>dB</b>
<b>Static current</b>		<b>50</b>		<b>mA</b>

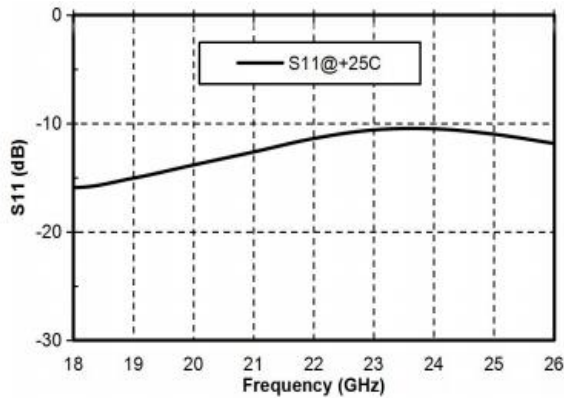
### Gain vs. Temperature



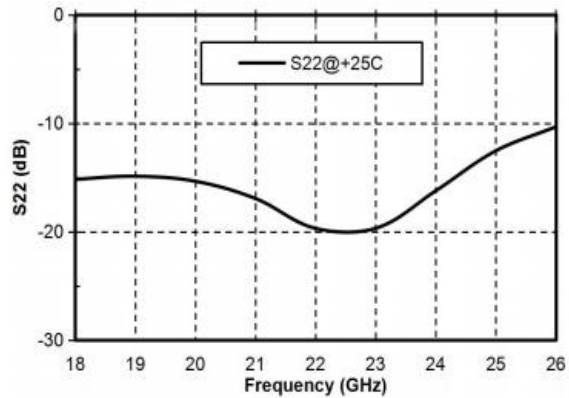
### Noise Figure vs. Temperature



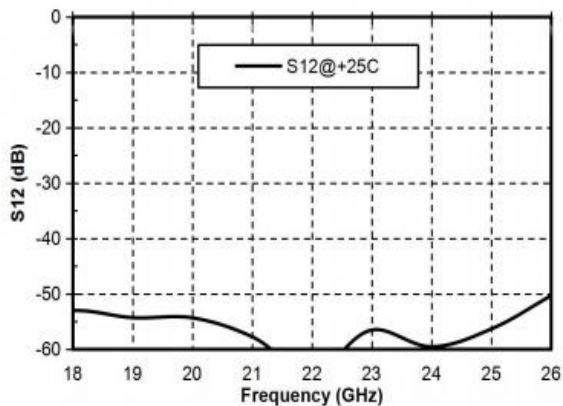
### Input Return Loss vs. Temperature



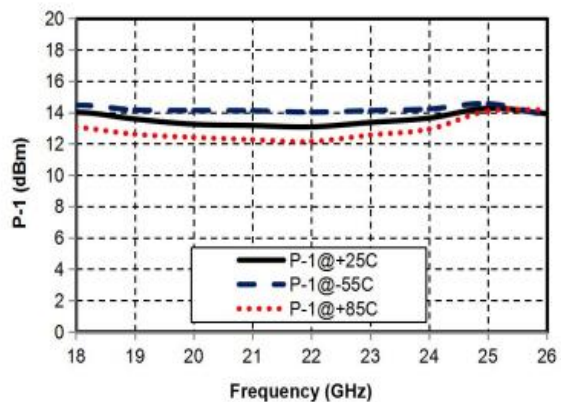
### Output Return Loss vs. Temperature



### Reverse Isolation vs. Temperature



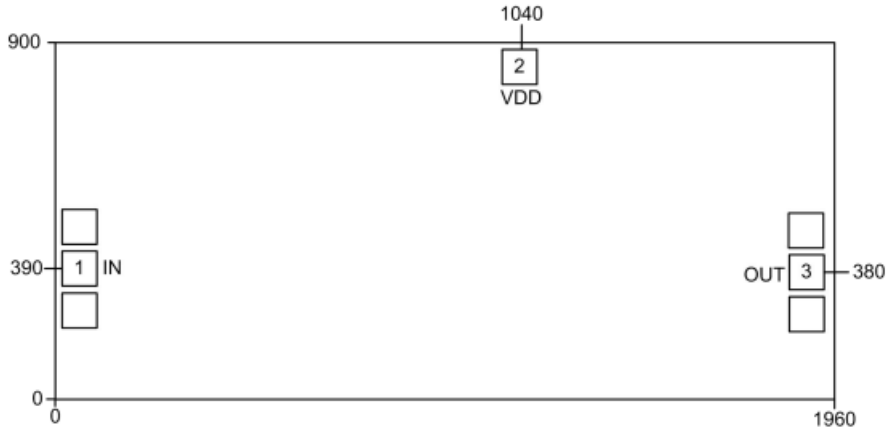
### P1dB vs. Temperature





### Outline Drawing:

All Dimensions in  $\mu\text{m}$

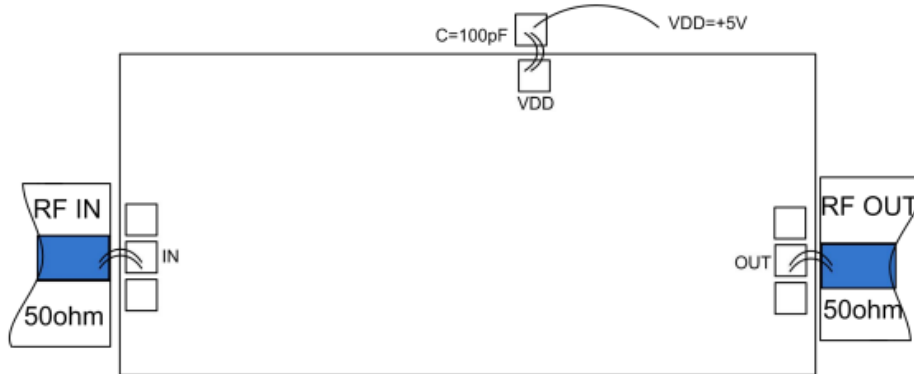


### Pad Description

Pad	Function	Description
1	RF IN	RF signal input terminal, no blocking capacitor required.
2	RF OUT	RF signal output terminal, no blocking capacitor required.
3	VDD	Amplifier drain bias; external 100pF bypass capacitor required.
Die bottom	GND	Die bottom must be connected to RF/DC ground.



### Assembly Drawing



#### Notes:

1. Die thickness: 100um
2. Typical bond pad is 100\*100  $\mu\text{m}^2$
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

#### Maximum Ratings:

1. Maximum drain voltage: +7V
2. Maximum input power: +20dBm
3. Operating temperature: -55°C to +85°C
4. Storage temperature: -65°C to +150°C